Vishay Semiconductors

High Performance Schottky Rectifier, 100 A



www.vishay.com

Cathode Anode

PowerTab[®]

PRODUCT SUMMARY				
Package	PowerTab [®]			
I _{F(AV)}	100 A			
V _R	100 V			
V _F at I _F	0.82 V			
I _{RM}	180 mA at 125 °C			
T _J max.	175 °C			
Diode variation	Single die			
E _{AS}	9 mJ			

FEATURES

- 175 °C max. operating junction temperature
- High frequency operation
- Low forward voltage drop
- Continuous high current operation
- Guard ring for enhanced ruggedness and long term reliability
- Screw mounting only
- AEC-Q101 qualified
- PowerTab[®] package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-100BGQ100HF4 Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
1	Rectangular waveform	100	А			
I _{F(AV)}	T _C	124	°C			
V _{RRM}		100	V			
I _{FSM}	t _p = 5 μs sine	6300	А			
	100 A _{pk} (typical)	0.77	V			
V _F	TJ	125	°C			
TJ	Range	-55 to +175	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-100BGQ100HF4	UNITS		
Maximum DC reverse voltage	V _R	100	V		
Maximum working peak reverse voltage	V _{RWM}	100			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_C = 124 °C, rectangular waveform		100	А	
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	6300	А	
non-repetitive surge current	IFSM	10 ms sine or 6 ms rect. pulse		800	~	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 4.5 mH		9	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		2	А	

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RoHS

COMPLIANT



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ELECTRICAL SPI	ECIFICATIONS
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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		VALUES		UNITS
FANAMETEN	STIVIDOL	1231 00	TYP.	MAX.	UNITS	
		50 A	T.I = 25 °C	0.83	0.86	
Forward voltage drop	V _{FM} ⁽¹⁾	100 A	1j=25 C	1.01	1.08	v
Forward voltage drop	VFM ()	50 A	T 405 %0	0.66	0.7	
		100 A	T _J = 125 °C	0.77	0.82	
Deveree leekege eurreet	I _{BM} ⁽¹⁾	T _J = 25 °C		22	300	μA
Reverse leakage current	IRM (")	T _J = 125 °C	V _R = Rated V _R	14	18	mA
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$, (test signal range 100 kHz to 1 MHz) 25 °C 1320				pF
Typical series inductance	L _S	Measured from tab to mounting plane 3.5 n			nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/µ				V/µs

Note

 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and temperature range	storage	T _J , T _{Stg}		-55 to +175	°C
Maximum thermal resis junction to case	stance,	R _{thJC}	DC operation	0.50	°C/W
Typical thermal resistar case to heatsink	nce,	R _{thCS}	Mounting surface, smooth and greased	0.30	0/10
Approximate weight				5	g
Approximate weight				0.18	oz.
Mounting torque	minimum			1.2 (10)	N·m
Mounting torque	maximum			2.4 (20)	(lbf \cdot in)
Marking device			Case style PowerTab [®] 100BGQ100H		Q100H

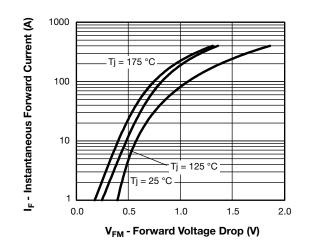
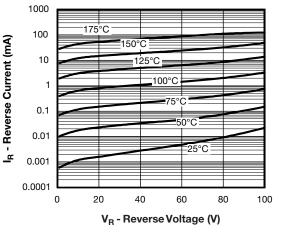
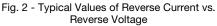


Fig. 1 - Maximum Forward Voltage Drop Characteristics





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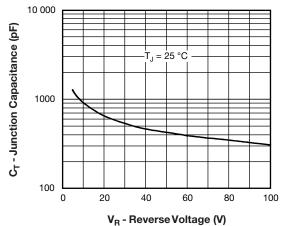
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VS-100BGQ100HF4

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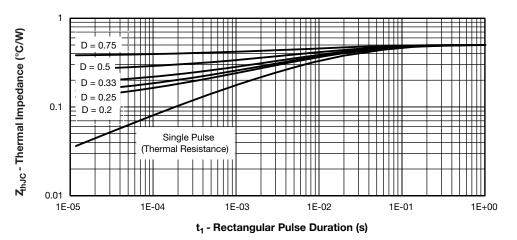
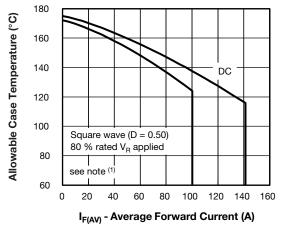
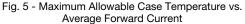
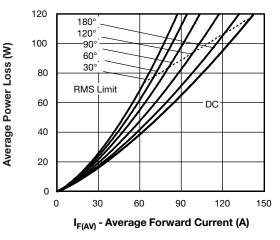


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics









Note

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ at \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ at \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;



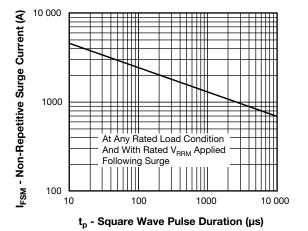
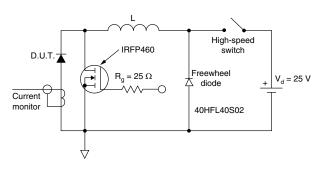


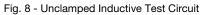
Fig. 7 - Maximum Non-Repetitive Surge Current

VS-100BGQ100HF4

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Antistatic plastic tube





ORDERING INFORMATION TABLE

VS-100BGQ100HF4

Device code	VS-	100	BGQ	100	н	F4
		(2)	(3)	(4)	(5)	6
	1 .	- Vis	hay Serr	niconduc	tors pro	oduct
	2 ·	- Cui	rrent rati	ng (100	= 100 A	N)
	3.	3 - Essential part number				
	4	4 - Voltage rating (100 = 100 V)				
	5	. н=	AEC-Q	101 qua	lified	
	6	- Env	vironmer	ntal digit	:	
		- F4	= RoHS	complia	int and t	otally le

ORDERING INFORMATI	ON (Example)		
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION

375

25

LINKS TO RELATED DOCUMENTS			
Dimensions www.vishay.com/doc?95240			
Part marking information	www.vishay.com/doc?95467		
Application note	www.vishay.com/doc?95179		

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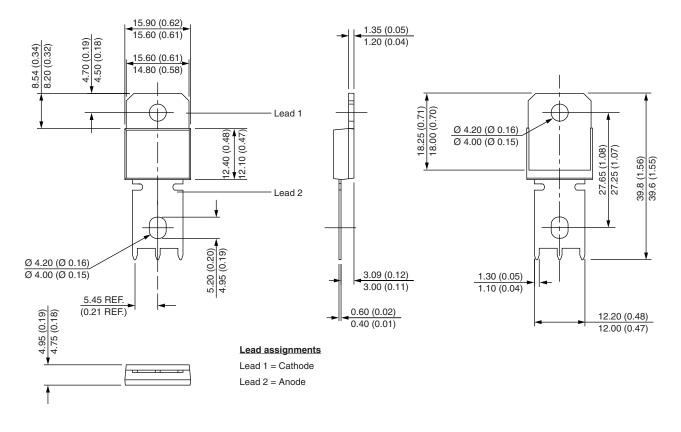
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DIMENSIONS in millimeters (inches)





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